

SANYO Semiconductors DATA SHEET

N-Channel Silicon MOSFET

2SK3489— General-Purpose Switching Device **Applications**

Features

- · Low ON-resistance.
- · 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

| | | I | | |
|-----------------------------|--------|--------------------------------------------------------|-------------|------|
| Parameter | Symbol | Conditions | Ratings | Unit |
| Drain-to-Source Voltage | VDSS | | 30 | V |
| Gate-to-Source Voltage | VGSS | | ±20 | V |
| Drain Current (DC) | ΙD | | 8 | Α |
| Drain Current (Pulse) | IDP | PW≤10μs, duty cycle≤1% | 32 | Α |
| Allowable Power Dissipation | Do. | Mounted on a ceramic board (250mm ² ×0.8mm) | 1.5 | W |
| | PD | Tc=25°C | 3.5 | W |
| Channel Temperature | Tch | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | | | I I - is |
|--------------------------------------------|-----------------------|-------------------------------------------|---------|------|-----|----------|
| | | | min | typ | max | Unit |
| Drain-to-Source Breakdown Voltage | V(BR)DSS | I _D =1mA, V _G S=0V | 30 | | | ٧ |
| Zero-Gate Voltage Drain Current | IDSS | V _{DS} =30V, V _{GS} =0V | | | 1 | μΑ |
| Gate-to-Source Leakage Current | IGSS | VGS= ±16V, VDS=0V | | | ±10 | μΑ |
| Cutoff Voltage | VGS(off) | V _{DS} =10V, I _D =1mA | 1.2 | | 2.6 | ٧ |
| Forward Transfer Admittance | yfs | V _{DS} =10V, I _D =4A | 3.5 | 5.1 | | S |
| Static Drain-to-Source On-State Resistance | RDS(on)1 | ID=4A, VGS=10V | | 37 | 48 | mΩ |
| | R _{DS} (on)2 | I _D =2A, V _G S=4V | | 63 | 88 | mΩ |
| Input Capacitance | Ciss | V _{DS} =10V, f=1MHz | | 460 | | pF |
| Output Capacitance | Coss | V _{DS} =10V, f=1MHz | | 95 | | pF |
| Reverse Transfer Capacitance | Crss | V _{DS} =10V, f=1MHz | | 75 | | pF |
| Turn-ON Delay Time | t _d (on) | See specified Test Circuit. | | 10 | | ns |
| Rise Time | tr | See specified Test Circuit. | | 12.5 | | ns |
| Turn-OFF Delay Time | t _d (off) | See specified Test Circuit. | | 31 | | ns |
| Fall Time | tf | See specified Test Circuit. | | 19 | | ns |

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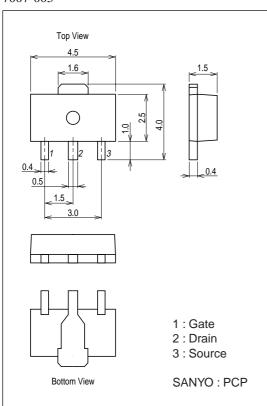
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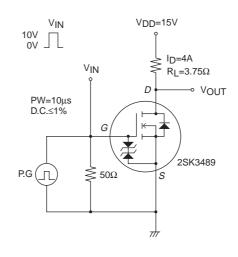
| Parameter | Symbol | Conditions | Ratings | | | Unit |
|-------------------------------|--------|----------------------------------------------------------------|---------|------|-----|------|
| | | | min | typ | max | Oill |
| Total Gate Charge | Qg | V _{DS} =10V, V _{GS} =10V, I _D =8A | | 8.5 | | nC |
| Gate-to-Source Charge | Qgs | V _{DS} =10V, V _{GS} =10V, I _D =8A | | 1.8 | | nC |
| Gate-to-Drain "Miller" Charge | Qgd | V _{DS} =10V, V _{GS} =10V, I _D =8A | | 1.3 | | nC |
| Diode Forward Voltage | VSD | IS=8A, VGS=0V | | 0.89 | 1.2 | V |

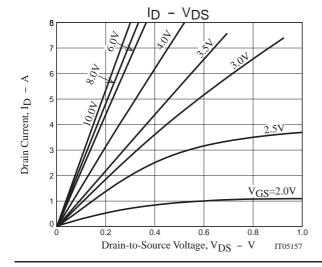
Package Dimensions

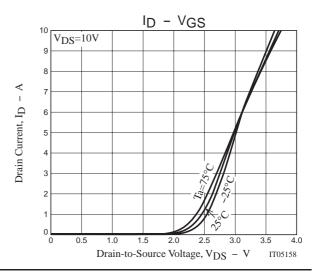
unit : mm 7007-003

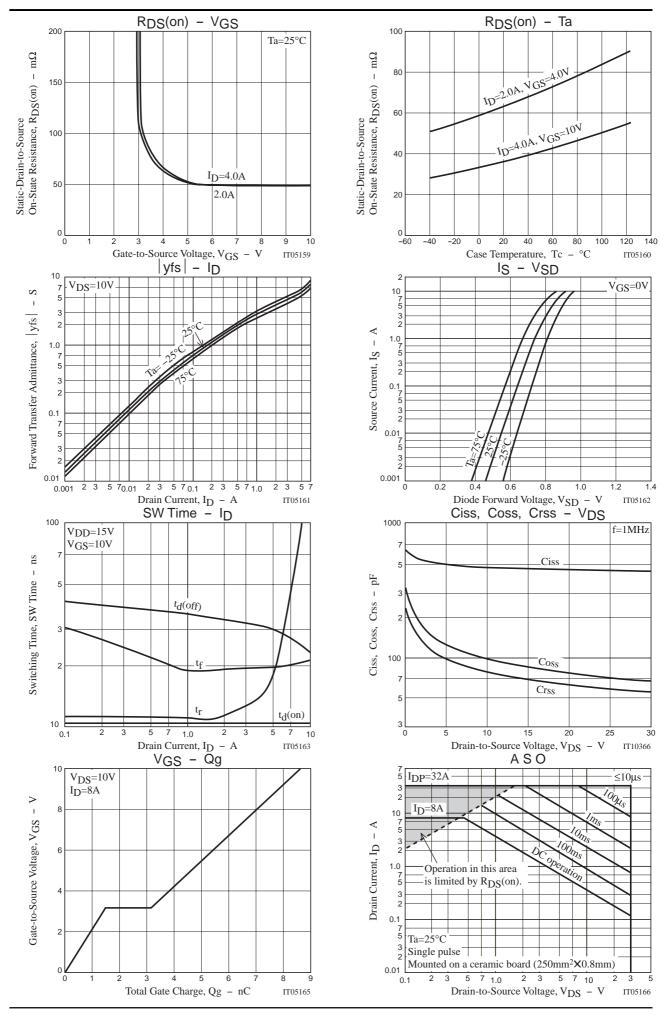


Switching Time Test Circuit

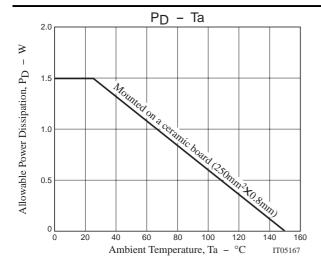


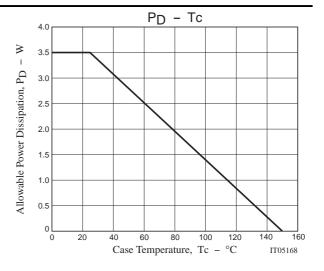






2SK3489





Note on usage: Since the 2SK3489 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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